

Features

Field Stop Trench gate IGBT、Low Collector-Emitter saturation voltage、High short circuit capability
Low switching losses

Version

Low noise

Application

Industrial Motor Drivers, Inverter, Welding, UPS

Status

Mass production

Specifications

Gate-Emitter voltage VCES [V]	Collector current IC [A]	Collector-Emitter saturation voltage VCE(sat) @Tj=25deg C typical limit	Collector-Emitter saturation voltage VCE(sat) @Tj=25deg C upper limit	Gate Voltage VGES [V]	Gate-Emitter threshold voltage VGE(th) lower limit [V]	Gate-Emitter threshold voltage VGE(th) upper limit [V]
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MMJC0A0J00xx

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		[V]	[V]			
1200	100	1.70	2.05	-30~30	5.20	6.60
Internal gate resistor Rgint typical limit [Ω]		Die size X [mm]	Die size Y [mm]		Junction temperature Tj [deg.C]	
7.5		10.26	9.60		-40~175	